PM82802C-28QW Datasheet

280V,3-Phase Bridge Pre Driver

Version：Rev.1.0

Release Date：2025-07-09

MetaWells Co., Ltd.

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General Description

PM82802C-28QW is a high-speed 3-phase gate driver for power MOSFET and IGBT devices with three independent high and low side referenced output channels. Built-in dead time protection and shoot-through protection prevent damage to the half-bridge. The UVLO circuits prevent malfunction when VCC and VBS are lower than the specified threshold voltage. A novel high-voltage BCD process and common-mode noise canceling technique provide stable operation of high-side drivers under high dV/dt noise conditions while achieving excellent negative transient voltage tolerance. Low-PW consumption is included so that standby mode may be used to set the chip into a low quiescent current state to realize long battery lifetime.

Features

- Integrated DBOOT(1)
- Floating channel designed for bootstrap operation
- Fully operational to +280 V
- Tolerant to negative transient voltage
- Gate drive supply range from 5V to 20V
- Independent 3 half-bridge drivers
- Low side output out of phase with inputs. High side outputs out of phase
- 3.3V logic compatible
- Lower di/dt gate drive for better noise immunity

Note：(1)When using internal diode bootstrap power supply, please match the capacitor and MOS, and fully test and verif.

Product Summary

V_{OFFSET}	280V max
I_O+/-	1.0 A / 1.2A
VCC	5V to 20V
ton/off (typ.)	310 & 120ns
Work Tem	-40 ~150 °C

Applications

- E-BIKE/electric power tool 3-phase motor driver
- Battery-powered mini/micro motor control
- General purpose inverter

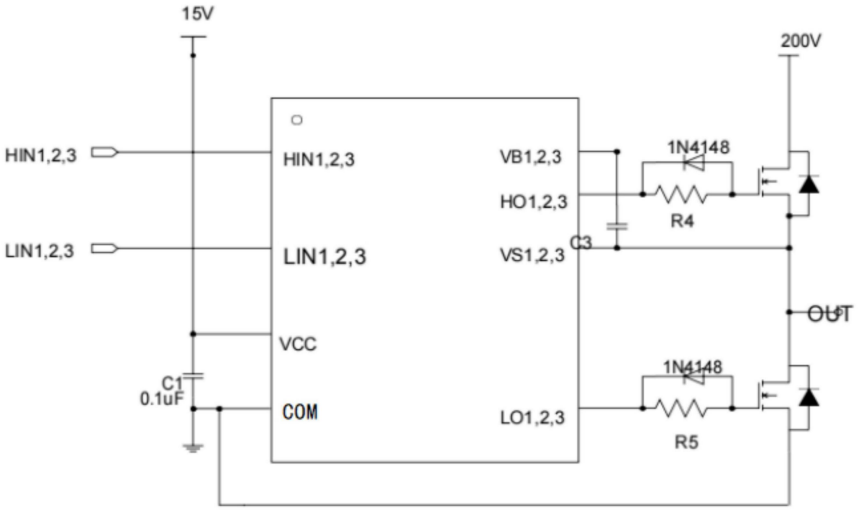
Ordering Information

ORDER NUMBER	Marking ID	Package	Description
PM82802C-28QW	A1 YM DNN	WQFN4x4-24	Halogen Free RoHS compliant in TB , 4000pcs

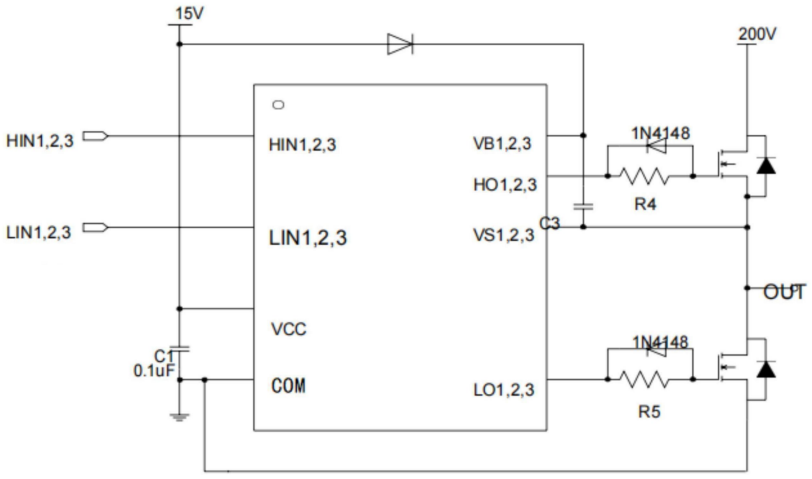
Marking Information

Marking	Package	Definition
A1 YM DNN	WQFN4x4-24	Product code : A1 Y : Year code M : Month code D : Day code NN: Serial Number

Typical Application



NO-BOOT Application

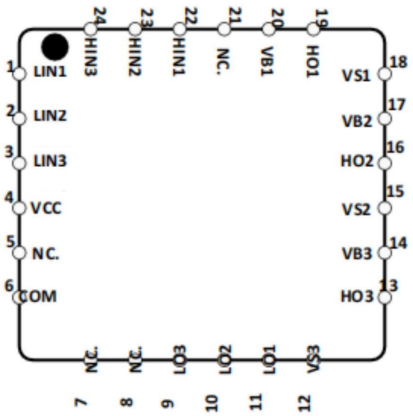


BOOT Application

Pin Function

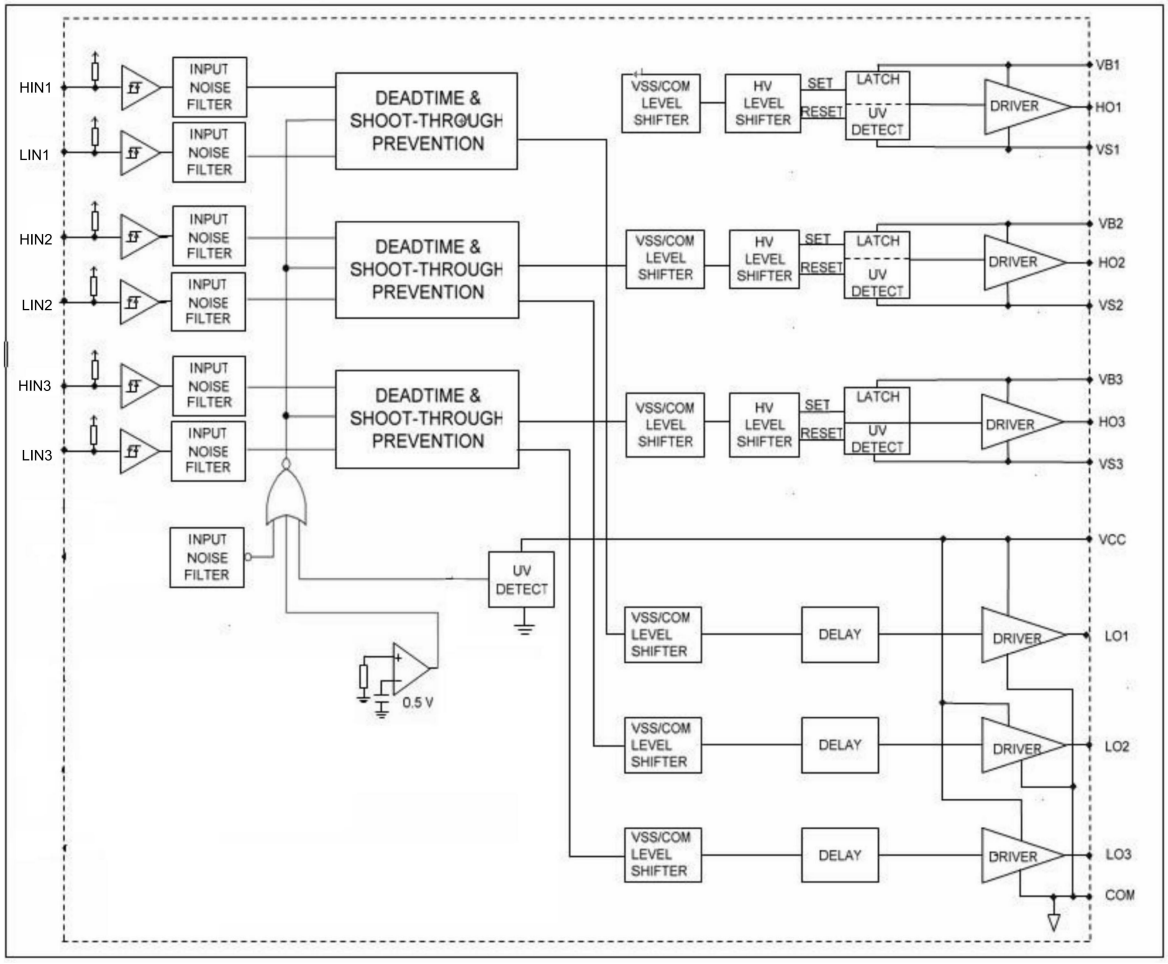
Number	Symbol	Description
1	VCC	Low side and logic fixed supply
2	HIN1,2,3	Logic inputs for high side gate driver outputs(HO1,2,3),in phase
3	LIN1,2,3	Logic inputs for high side gate driver outputs(LO1,2,3),in phase
4	COM	Logic Ground
5	VB1,2,3	High side floating supply
6	HO1,2,3	High side gate driver outputs
7	VS1,2,3	High voltage floating supply returns
8	LO1,2,3	Low side gate driver output

Packages



WQFN4x4-24

Function Block Diagram



Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min	Max	Units
VS	High side offset voltage	VB 1,2,3-25	VB 1,2,3+ 0.3	V
VB	High side floating supply voltage	-0.3	280	
VHO	High side floating output voltage	VS1,2,3 -0.3	VB 1,2,3+ 0.3	
VCC	Low side and logic fixed supply voltage	-0.3	25	
VLO1,2,3	Low side output voltage	-0.3	VCC+0.3	
VIN	Logic input voltage (HIN&LIN)	-0.3	VCC+0.3	
dV/dt	Allowable offset voltage slew rate	-	50	V/ns
PD	Package power dissipation @ T_A≤+25 °C	-	3.0	W
RthJA	Thermal resistance, junction to ambient	-	40	°C/W
TJ	Junction temperature	-	150	°C
TS	Storage temperature	-55	150	
TL	Lead temperature (soldering, 10 seconds)	-	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in figure . For proper operation the device should be used within the recommended conditions. All voltage parameters are absolute referenced to COM. The VS offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min	Max	Units
VB1,2,3	High side floating supply voltage	VS1,2,3+5	VS1,2,3+20	V
VS1,2,3	High side floating supply offset voltage	Note 1	200	
VHO1,2,3	High side output voltage	VS1,2,3	VB1,2,3	
VLO1,2,3	Low side output voltage	0	VCC	
VCC	Low side and logic fixed supply voltage	5	20	
VIN	Logic input voltage (HIN&LIN)	0	VCC	
TA	Ambient temperature	-40	125	°C

Note 1: Logic operational for VS of COM

Electrical Characteristics

(V_{CC}–COM)=(V_B–V_S)=15V. Ambient temperature T_A=25ºC unless otherwise specified. The V_{IN},T_H, V_I, and I_{IN} parameters are referenced to COM and are applicable to all channels. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads. The V_{CCUV} parameters are referenced to COM. The V_{BSUV} parameters are referenced to V_S.

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Low Side Power Supply Characteristics						
Quiescent VCC supply current	I_{QVCC1}	-	-	250	-	μA
operating VCC supply current	I_{VCCOP}	f=20KHz	-	300	-	
VCC supply under-voltage positive going Threshold	V_{CCUV+}	-	3.8	4.4	5	V
VCC supply under-voltage negative going threshold	V_{CCUV-}	-	3.6	4.2	4.8	
VCC supply under-voltage lockout hysteresis	V_{CCHYS}	-	0.1	0.2	-	
High Side Floating Power Supply Characteristics						
High side VBS supply under-voltage positive going threshold	V_{BSUV+}	-	3.8	4.4	5	V
High side VBS supply under-voltage negative going threshold	V_{BSUV-}	-	3.6	4.2	4.8	
High side VBS supply under-voltage lockout hysteresis6	$V_{BSUVHYS}$	-	0.1	0.2	-	
High side quiescent VBS supply current	I_{QBS}	V_{BS}=15V	25	45	65	μA
operating VBS supply current	I_{BSOP}	f=20KHz	-	160	-	
Offset supply leakage current	I_{LK}	V_B=V_S=200V V_{CC}=0V	-	-	10	
Logic Input Section						
Logic HIGH input voltage HIN1,2,3, LIN1,2,3	V_{IH}	-	2.5	-	-	V
Logic LOW input voltage HIN1,2,3, LIN1,2,3	V_{IL}	-	-	-	0.8	
Input positive going threshold	$V_{IN,TH+}$	-	-	1.9	-	
Input negative going threshold	$V_{IN,TH-}$	-	-	1.4	-	
Logic HIGH input bias current	I_{IN+}	V_{IN}=5V	-	25	-	μA
Logic LOW input bias current	I_{IN-}	V_{IN}=0	-	0	-	
Gate Driver Output Section						
High side output HIGH short-circuit pulse current	I_{HO+}	V_{HO}=V_S=0	-	1.0	-	A
High side output LOW short-circuit pulse current	I_{HO-}	V_{HO}=V_B=15V	-	1.2	-	
Low side output HIGH short-circuit pulse current	I_{LO+}	V_{LO}=0	-	1.0	-	
Low side output LOW short-circuit pulse current	I_{LO-}	V_{LO}=V_{CC}=15V	-	1.2	-	
Allowable negative VS voltage for HIN1,2,3 signal propagation to HO1,2,3	V_{SN}	V_{BS}=15V	-	- 12	-	V

Electrical Characteristics

(V_{CC} – COM)=(V_B – V_S)=15V ,VS1,2,3=COM, and Cload=1nF unless otherwise specified, ambient temperature T_A=25° C.

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Turn-on propagation delay	t_{on}	$V_{HIN1,2,3}$ or $V_{LIN1,2,3}$=5V, $V_{S1,2,3}$=0	-	380	-	ns
Turn-off propagation delay	t_{off}	$V_{HIN1,2,3}$ or $V_{LIN1,2,3=0}$, $V_{S1,2,3}$=0	-	180	-	
Turn-on rise time	t_r	$V_{HIN1,2,3}$ or $V_{LIN1,2,3}$=5V,$V_{S1,2,3}$=0	-	50	-	
Turn-off fall time	t_f	$V_{HIN1,2,3}$ or $V_{LIN1,2,3}$=0, $V_{S1,2,3}$=0	-	25	-	
Dead time	DT	$V_{HIN1,2,3}$ or $V_{LIN1,2,3}$=0 and 5V, without external dead time	-	200	250	
Dead time matching (all six channels)	MDT	without external dead time	-	-	50	
Delay matching (all six channels)	MT	external dead time > 1000ns	-	-	50	
Output pulse-width matching	PM	external dead time > 1000ns, PW_{IN}=10μs, PM=PW_{OUT}–PW_{IN}	-	-	50	

Low Side Power Supply: VCC

VCC is the low side supply and it provides power to both input logic and low side output power stage. The built-in under- voltage lockout circuit enables the device to operate at sufficient power when a typical VCC supply voltage higher than V_{CCUV+} is present, shown as Figure. 1. The PM82802C-28QW shuts down all the gate driver outputs, when the VCC supply voltage is below V_{CCUV-} V, shown as Figure. 1. This prevents the external power devices against extremely low gate voltage levels during on-state which may result in excessive power dissipation.

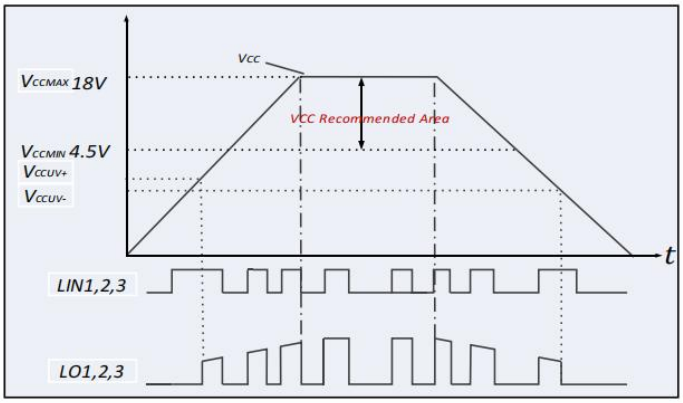


Figure. 1 VCC supply UVLO operating area

High Side Power Supply: VBS (VB1-VS1, VB2-VS2, VB3-VS3)

VBS is the high side supply voltage. The total high side circuitry may float with respect to COM following the external high side power device emitter/source voltage. Due to the internal low power consumption, the entire high side circuitry may be supplied by bootstrap topology connected to VCC, and it may be powered with small bootstrap capacitors. The device operating area as a function of the supply voltage is given in Figure. 2.

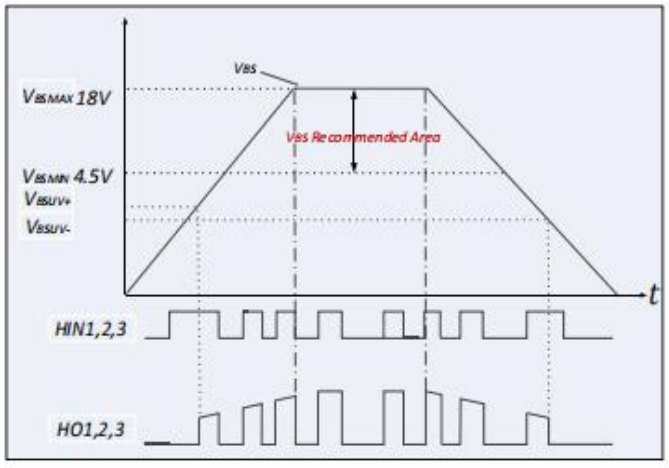


Figure. 2 VBS supply UVLO operating area

Low side And High Control Input Logic: HIN&LIN (HIN1, 2, 3/LIN1, 2, 3)

The Schmitt trigger threshold of each input is designed low enough to guarantee LSTTL and CMOS compatibility down to 3.3V controller outputs. Input Schmitt trigger and advanced noise filtering provide noise rejection of short input pulses. An internal pull-down resistor of about 220kΩ(positive logic) pre-biases each input during VCC supply start-up state. The minimum recommended input pulse-width is 300ns for proper operation of the driver.

Shoot- Through Prevention

The PM82802C-28QW is equipped with shoot-through protection circuitry (also known as cross conduction prevention circuitry). Figure. 3 shows how this protection circuitry prevents both the high- and low-side switches from conducting at the same time. When the inputs controlling both high-side and low-side drivers are both logic HIGH, then both driver outputs are pulled down to logic LOW to shut down two power devices in the same bridge.

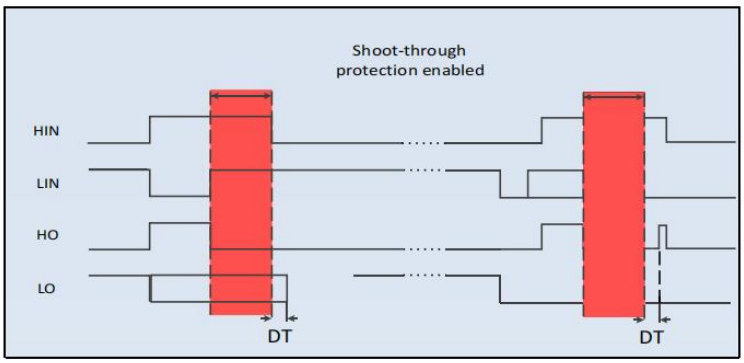


Figure. 3 Shoot-through prevention

Dead Time Protection

The PM82802C-28QW features integrated fixed dead time protection circuitry. The dead time feature inserts a time period (a minimum dead time) in which both the high- and low-side power switches are held off. This is done to ensure that the power switch has fully turned off before the second power switch is turned on. This minimum dead time is automatically inserted whenever the external dead time is shorter than DT. External dead times larger than DT are not modified by the gate driver. Figure. 4 illustrates the dead time period and the relationship between the output gate signals.

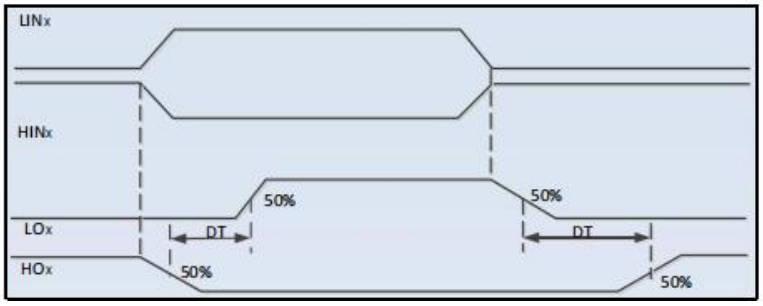
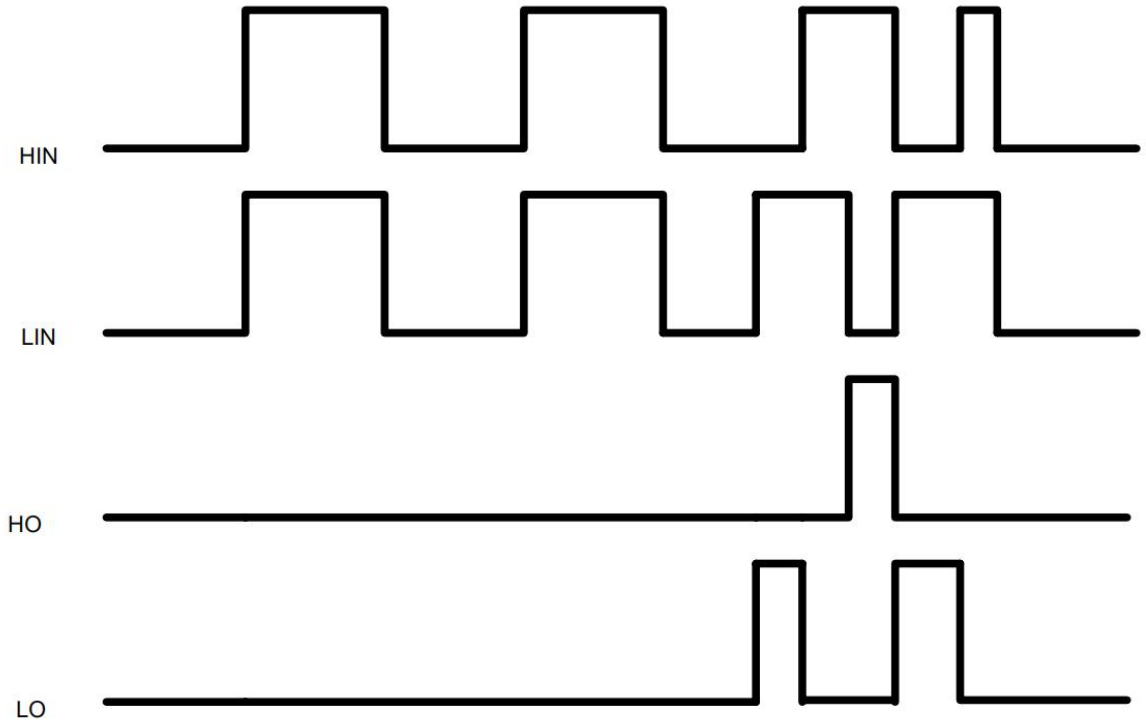


Figure. 4 Dead time protection

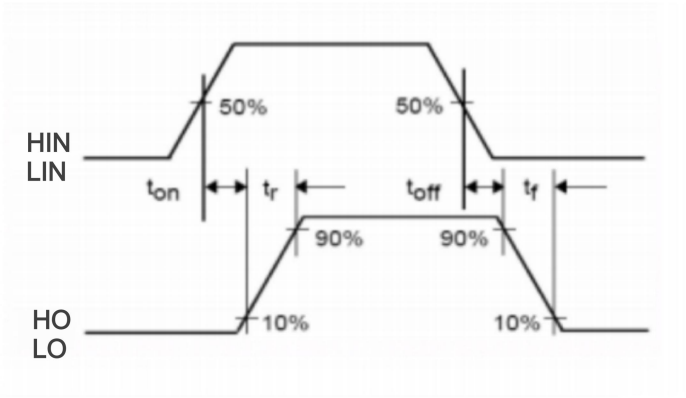
Gate Driver (HO1, 2, 3/ LO1, 2, 3)

Low side and high side driver outputs are specifically designed for pulse operation and dedicated to drive power devices such as IGBT and power MOSFET. Low side outputs (i.e. LO1, 2, 3) are state triggered by the respective inputs, while high side outputs (i.e. HO1,2,3) are only changed at the edge of the respective inputs. After releasing from an under- voltage condition of the VBS supply, a new turn-on signal (edge) is necessary to activate the respective high side output. In contrast, after releasing from an under-voltage condition of the VCC supply, the low side outputs may directly switch to the state of their respective inputs without the additional constraints of the high side driver.

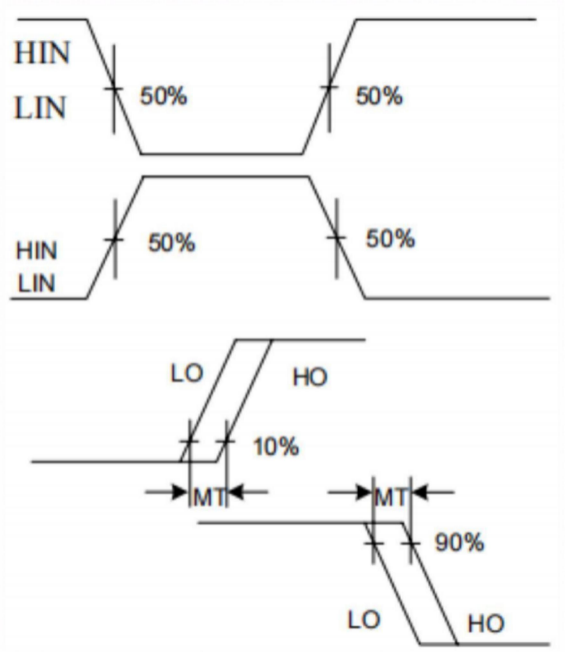
Typical Performance Characteristics



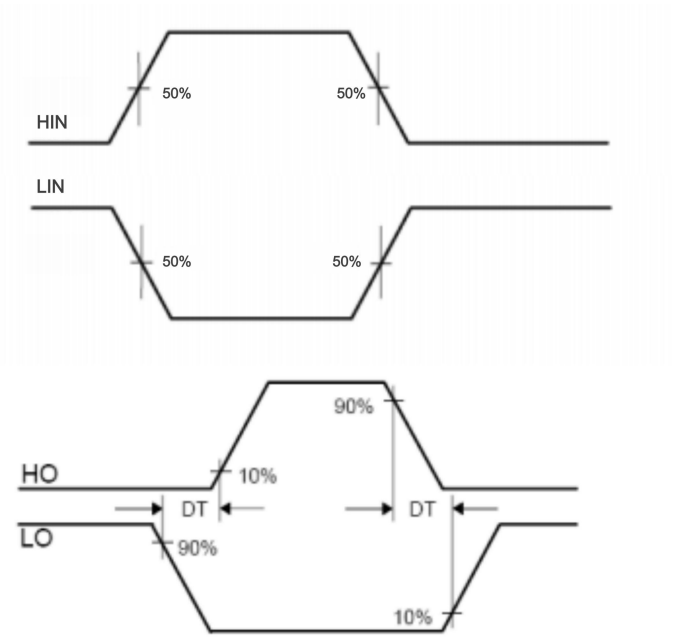
Time Waveform



Switching Time Waveform Definitions



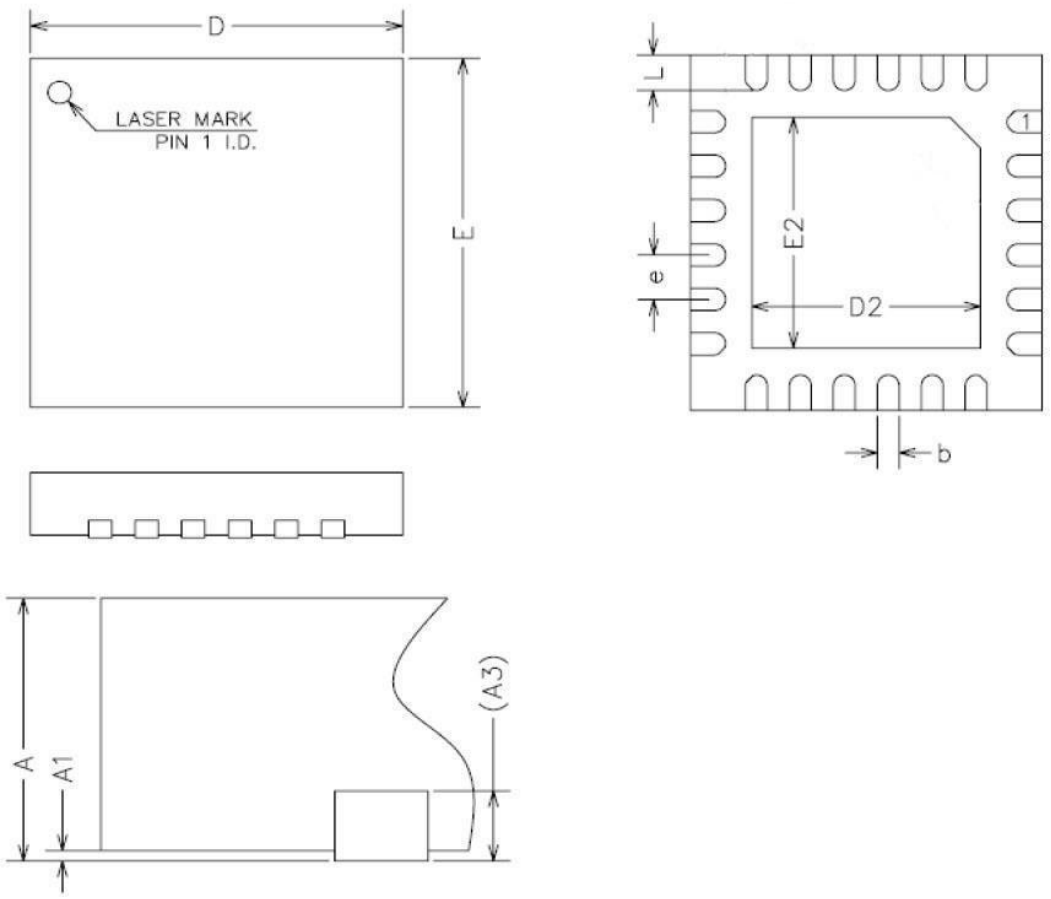
Deadtime Waveform Definitions



Delay matching time Definition

Physical Dimensions

Unit:mm



Symbol	Dimensions(mm)		
	Min.	Nom.	Max.
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3		0.20 REF	
b	0.18	0.25	0.30
D		4.00 BSC	
D2	2.50	2.65	2.80
E		4.00 BSC	
E2	2.50	2.65	2.80
e		0.50 BSC	
L	0.35	0.40	0.45

Notes:

1. All dimensions refer to JEDEC MO-220 WGGD-6
2. All dimensions are in mm

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